# ランダムな 3 次元トポロジカル物質の相図とスケーリング則 

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－T．Ohtsuki and T．Ohtsuki：J．Phys．Soc．Jpn，85， 123706 （2016），86， 044708 （2017）．
－T．Mano and T．Ohtsuki：J．Phys．Soc．Jpn．，86， 113704 （2017）．
－S．Liu，T．Ohtsuki，R．Shindou：Physical Review Letters 116， 066401 （2016）．
－X．Luo，B．Xu，T．Ohtsuki，R．Shindou：Physical Review B 97， 045129 （2018）．
－X．Luo，T．Ohtsuki，R．Shindou：Physical Review B 98， 020201 （2018）．

## Outline

- What are Chern insulators (CI)? $\rightarrow$ 2D quantum Hall system
- Construction of 3D Weyl semimetal from 2D CI
- Phase diagram of 3DWSM
- Transfer matrix method
- Machine learning (cf. previous talk)
- Scaling behaviors
- Density of state scaling
- Unconventional scaling



## Weyl semimetal

- $H=v\left(p-p_{0}\right) \cdot \sigma, E=v\left|p-p_{0}\right|$

- Many 3D examples have been discovered in the last few years. One possible realization is to stack two dimensional Chern insulator $\rightarrow$ today's talk
- Effect of randomness?
- Scaling theory of semi-metal to metal transition induced by disorder
- Other unconventional scaling behaviors


# Phase transition for layered Chern insulator 

2D Chern Insulator


Weyl semimetal<br>$E=v k$



## What are Chern insulators?

- Band gap insulator with peculiar edge states.
- (pseudo) magnetization is present, time reversal symmetry is broken.
- quantized Hall conductivity
- Belong to the quantum Hall universality class but without Landau levels.
- When stacked to the $3^{\text {rd }}$ direction, it shows rich phase diagram.


## Model

- We start with a 2D spinless tight-binding model on a cubic (square) lattice, which comprises of $s$-orbital and $p_{+} \equiv p_{x}+\mathrm{i} p_{y}$ orbital. (is a Chern insulator with suitable parameters)
- We then pile it up along $z$-direction with an inter-layer coupling amplitude $\beta$.




## 2D Chern insulator

- proposed by Haldane, PRL. 61, 2015 ('88).
- Qi-Wu-Zhang model,PRB. 74, 085308 (‘06)

$$
\begin{array}{rlr}
\mathcal{H}= & \sum_{\boldsymbol{x}}\left(\left[\epsilon_{s}+v_{s}(\boldsymbol{x})\right] c_{\boldsymbol{x}, s}^{\dagger} c_{\boldsymbol{x}, s}+\left[\epsilon_{p}+v_{p}(\boldsymbol{x})\right] c_{\boldsymbol{x}, p}^{\dagger} c_{\boldsymbol{x}, p}\right) & \\
& +\sum_{\boldsymbol{x}}\left(-\sum_{\mu=x, y}\left(t_{s} c_{\boldsymbol{x}+\boldsymbol{e}_{\mu}, s}^{\dagger} c_{\boldsymbol{x}, s}-t_{p} c_{\boldsymbol{x}+\boldsymbol{e}_{\mu}, p}^{\dagger} c_{\boldsymbol{x}, p}\right)\right. & -W / 2<v_{s, x}, v_{\mathrm{p}, \boldsymbol{x}}<W / 2 \\
& +t_{s p}\left(c_{\boldsymbol{x}+\boldsymbol{e}_{x}, p}^{\dagger}-c_{\boldsymbol{x}-\boldsymbol{e}_{x}, p}^{\dagger}\right) c_{\boldsymbol{x}, s} & \varepsilon_{s}=-0.5 \\
& \left.-i t_{s p}\left(c_{\boldsymbol{x}+\boldsymbol{e}_{y}, p}-c_{\boldsymbol{x}-\boldsymbol{e}_{\boldsymbol{y}}, p}\right) c_{\boldsymbol{x}, s}+\text { h.c. }\right) & \varepsilon_{p}=0.5 \\
t_{s}=t_{p}=0.25 \\
t_{s p}=1 / 3
\end{array}
$$

$$
H_{\mathbf{k}}=a_{\mu} \sigma^{\mu} \text { with }\left\{\begin{array}{l}
a_{0}=0 \\
\left(a_{1}, a_{2}\right)=-\frac{2}{3}\left(\sin k_{y}, \sin k_{x}\right) \\
a_{3}=\frac{1}{2}-\frac{1}{2}\left(\cos k_{x}+\cos k_{y}\right)
\end{array}\right.
$$

$C h=\frac{1}{4 \pi} \iint d k_{x} d k_{y} \frac{\left(\partial_{x} a \times \partial_{y} a\right) \cdot a}{|a|^{3}}$

## Hall conductivity

- $G_{x y} /\left(e^{2} / h\right)$
$=\operatorname{sgn}\left(\left(\varepsilon_{\mathrm{p}}-\varepsilon_{\mathrm{s}}\right) / 4 t_{\mathrm{sp}}\right)$ for $\left|\left(\varepsilon_{\mathrm{p}}-\varepsilon_{\mathrm{s}}\right) / 2\left(t_{\mathrm{s}}+t_{\mathrm{p}}\right)\right|<2$
$=0$

$$
G_{x y} /\left(e^{2} / h\right)=1
$$



$$
G_{x y} /\left(e^{2} / h\right)=0
$$

Introduce disorder $\rightarrow$ Chern insulator to Anderson insulator transition

## Stacking 2D Chern insulators

- finite region of diffusive metal regime appears with the increase of interlayer coupling


Cf. Layered quantum Hall system:
T. Ohtsuki et al., J. Phys. Soc. Jpn. 62, 224 (1993).
J. T. Chalker et al., Phys. Rev. Lett. 75, 4496 (1995).

## phase diagram w.r.t. interlayer coupling and disorder

Liu, Ohtsuki, Shindou, PRL '16


## Layered Chern Insulator

$$
\begin{equation*}
\boldsymbol{H}(\boldsymbol{k})=a_{0} \sigma_{0}+\boldsymbol{a} \cdot \boldsymbol{\sigma} \tag{7}
\end{equation*}
$$

with $\boldsymbol{\sigma}=\left(\sigma_{x}, \sigma_{y}, \sigma_{z}\right)$ are Pauli matrices and

$$
a_{0}(\boldsymbol{k})=\frac{\epsilon_{s}+\epsilon_{p}}{2}+\left(t_{p}-t_{s}\right)\left(\cos k_{x}+\cos k_{y}\right)-\left(t_{s}^{\prime}+t_{p}^{\prime}\right) \cos k_{z}
$$

$$
a_{3}(k)=\frac{\epsilon_{s}-\epsilon_{p}}{2}-\left(t_{p}+t_{s}\right)\left(\cos k_{x}+\cos k_{y}\right)-\left(t_{s}^{\prime}-t_{p}^{\prime}\right) \cos k_{z}
$$

$a_{2}(k)=-2 t_{s p} \sin k_{y}$,
$a_{1}(k)=-2 t_{s p} \sin k_{x}$,
For simplicity,

$$
t_{s}^{\prime}+t_{p}^{\prime}=0, t_{s}-t_{p}=0 \quad \varepsilon_{s}-\varepsilon_{p}=-2\left(t_{s}+t_{p}\right)=-4 t_{s}
$$

$E= \pm\left(a_{1}^{2}+a_{2}^{2}+a_{3}^{2}\right)^{1 / 2}$


## clean system



Why is Weyl semimetal robust against randomness?
(by Syzranov et al., PHYSICAL REVIEW B 91, 035133 (2015) )

- effective fluctuation $\Delta W=W /(\lambda / a)^{d / 2}=W(k a)^{d / 2}$
- Kinetic Energy $E=b k^{\alpha}$
- At band edge, $k \rightarrow 0, E \gg \Delta W$ for $d-2 \alpha>0$
- In case of Schrodinger Eq. $(\alpha=2)$, randomness becomes relevant at band edge when $d<4$.
- In case of Dirac/Weyl semimetal ( $\alpha=1$ ), randomness becomes irrelevant at band edges when $d>2$.
- RG analysis, Goswami et al. '11, Syzranov et al. '16


## How did we determine the phase diagram?

- Localization length calculation by transfer matrix method along z-direction.



## 3D Weyl semimetal (3DWSM)

- semimetal $\Rightarrow$ Existence of Dirac/Weyl nodes
- Pairs of Weyl nodes move as a function of mass and disorder
- Fermi arcs appear on specific surfaces



# $|\psi(\vec{x})|^{2}$ <br> diagonalization for $80 \times 80 \times 80$ system 


$\beta=0.45$
$\mathrm{W}=0.8$
$\beta=0.45$
$\mathrm{W}=1.7$
$\beta=0.6$
W=1.5

# Phase diagram for 3DWSM: real space analysis 

T. Ohtsuki, T. Ohtsuki, JPSJ ‘16, ‘17

$E \approx \mathbf{0}, \mathrm{fbc}$ for $\boldsymbol{x}$ direction

S.Liu, T.Ohtsuki, R.Shindou, PRL'16


Integrate along $y$


- Can we distinguish WSM II /WSMIII?


## Application to Weyl semimetals

$32 \times 32 \times 32$, Conv-Pool-Conv-Pool (Mano et al., unpublished) $|\psi(\vec{x})|^{2}$ vs. $|\psi(\vec{k})|^{2}$


DM/CI/WSM (II, III), real space


DM/CI/WSM (II, III), $\boldsymbol{k}$-space


## phase diagram



# Density of state scaling for WSM to Metal 

 (Kobayashi et al., PRL14, Dirac semimetal in 3D TI)Number of states below $\varepsilon \quad N(\epsilon, L)=F\left(L / \xi, \epsilon / \epsilon_{0}\right)$,
Relate energy scale to length scale via $z$ $\epsilon_{0} \propto \xi^{-z}$.

In thermodynamic limit,

$$
N(\epsilon, L)=(L / \xi)^{d} f\left(\epsilon \xi^{z}\right) .
$$

DOS per volume is derived as

$$
\rho(\epsilon)=\frac{1}{L^{d}} \frac{d N(\epsilon, L)}{d \epsilon},
$$

$$
\rho(\epsilon)=\rho(-\epsilon)=\xi^{z-d} f^{\prime}\left(|\epsilon| \xi^{z}\right)
$$

Distance from the critical point $\delta=\left|W-W_{\mathrm{c}}\right| / W_{\mathrm{c}}$

$$
\xi \sim \delta^{-\nu}
$$

$$
\rho(\epsilon) \sim \delta^{(d-z) \nu} f^{\prime}\left(|\epsilon| \delta^{-z \nu}\right)
$$

From $\rho(\epsilon) \sim \delta^{(d-z) \nu} f^{\prime}\left(|\epsilon| \delta^{-z \nu}\right)$.
Weyl/Dirac SM $\rho(\epsilon) \sim \delta^{(d-z) \nu}\left(|\epsilon| \delta^{-z \nu}\right)^{d-1}=|\epsilon|^{d-1} \delta^{-(z-1) d \nu}$. metallic $\quad \rho(0) \sim \delta^{(d-z) \nu}\left(|\epsilon| \delta^{-z \nu}\right)^{0}=\delta^{(d-z) \nu}$. Fradkin, '86

Critical point

$$
\rho(\epsilon) \sim \delta^{(d-z) \nu}\left(|\epsilon| \delta^{-z \nu}\right)^{(d-z) / z}=|\epsilon|^{(d-z) / z} .
$$




$$
\begin{aligned}
(3-z) / z & =1.00 \pm 0.15 \\
z & =1.5 \pm 0.1
\end{aligned}
$$

## Estimates of exponents

For DSM

$$
\rho(\epsilon) \sim c(\delta)|\epsilon|^{2},
$$

For metal

$$
c(\delta)^{-1} \sim \delta^{3(z-1) \nu_{\mathrm{DSM}}}
$$

$\rho(0) \sim \delta^{(d-z) \nu}$

$$
v \sim \delta^{(z-1) \nu} \approx \delta^{0.4}
$$




$$
\begin{aligned}
3(z-1) \nu_{\mathrm{DSM}} & \simeq 1.16 \pm 0.05, \\
\therefore \nu_{\mathrm{DSM}} & \simeq 0.81 \pm 0.21 .
\end{aligned}
$$

$$
\begin{aligned}
(3-z) \nu_{\mathrm{M}} & \simeq 1.36 \pm 0.09 \\
\therefore \nu_{\mathrm{M}} & \simeq 0.92 \pm 0.13
\end{aligned}
$$

## single parameter scaling plot

$$
\rho(\epsilon) \sim \delta^{(d-z) \nu} f^{\prime}\left(|\epsilon| \delta^{-z \nu}\right) .
$$



## Scaling laws

Distance from the critical point: $\quad \delta=\left|W-W_{\mathrm{c}}\right| / W_{\mathrm{c}}$
Diverging length scale: $\xi \sim \delta^{-\nu}$,
Vanishing energy scale: $\epsilon_{0} \propto \xi^{-z}$.

## Weyl semimetal

## Diffusive Metal

DoS @ $\varepsilon=0$
0
$\delta^{(d-z) v}$
Effective velocity
$\delta^{(z-1) v}$
Diffusion Constant @ $\varepsilon=0$
$\infty$
Conductivity $\sigma$ @ $\varepsilon=0$
$\delta^{(d-2) v}$
$\delta^{(d-2) v}$
The same scaling law
DoS @ Critical point: $\rho(\varepsilon) \sim|\varepsilon|^{(d-z) / z}$

## Conductivity scaling: from WSM side

Weyl semimetal to $W_{c}: D=v^{2} \tau / d, \rho \propto 1 / \tau \rightarrow$

$$
\sigma(E=0) \propto \bar{v}^{2} \text { with } \bar{v} \propto \delta^{(z-1) \nu}
$$

assuming $z=d / 2$, we recover $\quad \sigma(0) \sim \delta^{(d-2) \nu}$,


## Scaling behaviors in other parts of the phase diagram

- Quantum Multicritical point (QMCP) is encompassed by three phases: band insulator, renormalized Weyl semimetal and diffusive metal phases
$\checkmark$ BI-WSM phase transition is controlled by FPO in the clean limit; unconventional scaling X. Luo, et. al. Phys. Rev. B 98, 020201(R) (2018)


Layered Chern insulator


## Magnetic dipole model for BI-WSM transition

$$
\begin{gathered}
\mathcal{H}_{\mathrm{eff}}=\int d^{2} \boldsymbol{x}_{\perp} d x_{3} \psi^{\dagger}(\boldsymbol{x})\left\{-i v\left(\partial_{1} \boldsymbol{\sigma}_{1}+\partial_{2} \boldsymbol{\sigma}_{2}\right)\right. \\
\left.+\left((-i)^{2} b_{2} \partial_{3}^{2}-m\right) \boldsymbol{\sigma}_{3}\right\} \psi(\boldsymbol{x}),
\end{gathered}
$$


$\mathrm{m}>0$ : WSM phase
MM and AM locate at $\left(p_{1}, p_{2}, p_{3}\right)=\left(0,0, \pm \sqrt{m / b_{2}}\right)$.

B. Roy, et.al. arXiv:1610.08973 (2016) X. Luo, et. al. Phys. Rev. B 97, 045129 (2018)

## Effect of Disorders on Magnetic dipole model

$$
\begin{gathered}
\mathcal{H}_{\mathrm{eff}}=\int d^{2} \boldsymbol{x}_{\perp} d x_{3} \psi^{\dagger}(\boldsymbol{x})\left\{-i v\left(\partial_{1} \boldsymbol{\sigma}_{1}+\partial_{2} \boldsymbol{\sigma}_{2}\right)\right. \\
\left.+\left((-i)^{2} b_{2} \partial_{3}^{2}-m\right) \boldsymbol{\sigma}_{3}\right\} \psi(\boldsymbol{x})
\end{gathered}
$$

the model has a quadratic dispersion along the dipole direction, and a linear dispersion along the in-plane direction in the clean limit

$b$ : block size in $k$-space

## unconventional scaling form of conductance along BIWSM transition

$$
\begin{gathered}
x_{z}^{\prime}=b^{1 / 2} x_{z} \\
x_{\perp}^{\prime}=b x_{\perp}
\end{gathered}
$$

$$
\left\{\begin{array}{l}
\rho^{\prime}=b^{-\left(d-\frac{1}{2}-z\right)} \rho \quad\left(V^{\prime}=b^{\left.d-\frac{1}{2} V\right)}\right. \\
D_{\perp}^{\prime}=b^{-(z-2)} D_{\perp}, D_{z}^{\prime}=b^{-(z-1)} D_{z} .
\end{array}\right.
$$

With Einstein relation: $\sigma_{\mu}=e^{2} D_{\mu} \rho$, we obtain:

$$
\sigma_{\perp}^{\prime}=b^{-d+\frac{5}{2}} \sigma_{\perp}, \sigma_{z}^{\prime}=b^{-d+\frac{3}{2}} \sigma_{z}
$$

$$
\begin{aligned}
& G_{\perp}^{\prime}\left(L_{z}^{\prime}, L_{\perp}^{\prime}, \Delta^{\prime}, m^{\prime}\right)=G_{\perp}\left(L_{z}, L_{\perp}, \Delta, m\right), \\
& G_{z}^{\prime}\left(L_{z}^{\prime}, L_{\perp}^{\prime}, \Delta^{\prime}, m^{\prime}\right)=G_{z}\left(L_{z}, L_{\perp}, \Delta, m\right), \begin{array}{l}
\text { set } m \text { to be tiny, } \\
m^{\prime}=b^{-1} m=1
\end{array} \\
& \left.\begin{array}{l}
L_{z}^{\prime}=b^{\frac{1}{2}} L_{z} \\
L_{\perp}^{\prime}=b L_{\perp} \\
\Delta^{\prime}=b^{-y_{\Delta}} \\
m^{\prime}=b^{-1} m
\end{array}\right) G_{\mu}\left(L_{z}, L_{\perp}, m\right)=\Phi_{\mu}\left(m^{1 / 2} L_{z}, m L_{\perp}\right)
\end{aligned}
$$

## numerical test for unconventional scaling form of conductance




## anisotropic system size: <br> $L_{\perp}=\eta L_{z}^{2}$

$$
G_{\mu}\left(L_{z}, L_{\perp}, m\right)=f\left(m L_{z}^{2}\right) \quad \mu=z, \perp \quad m=\beta-\beta_{c}
$$

Phys. Rev. B 97, 045129 (2018).
Phys. Rev. B 98, 020201(R) (2018).

## Summary

- Rich phase diagram: Chern insulator, Anderson insulator, Weyl semimetal, diffusive metal
- Phase diagram: machine learning in real and kspace
- Scaling behaviors: nontrivial behaviors of
- Density of states scaling for WSM/Metal, similar to Coulomb glass/metal transition.
- Conductivity scaling.
- 3D Topological insulator?


